	Type	L #	Hits	Search Text	DBs
1	BRS	L1	1857	vertical adj transistor	USPAT
2	BRS	L2	982	1 and memory	USPAT
3	BRS	L3	5	second adj planar adj transistor	USPAT
4	BRS	L4	4	1 and (multi adj2 junction)	USPAT
5	BRS	L5	4	("5952692" | "6475857" | "6528896" | "6635921").PN.	US-PGPUB; USPAT; USOCR
6	BRS	L6	0	("7042107").URPN.	USPAT
7	IS&R	L7	1	("5604357").PN.	USPAT
8	IS&R	L8	1	("6635921").PN.	USPAT
9	IS&R	L9	1	("6707089").PN.	USPAT
10	BRS	L10	2	("5952692" | "6072718").PN.	US-PGPUB; USPAT; USOCR
11	BRS	L11	0	("6707089").URPN.	USPAT

	Type	L #	Hits	Search Text	DBs
12	BRS	L12	70	("20010013621" | "20030043637" | "20030207032" | "20030207540" | "20050023602" | "20050023603" | "20050026349" | "4295150" | "4412902" | "4688078" | "4757360" | "4780424" | "4939559" | "5071782" | "5073519" | "5350738" | "5399516" | "5418389" | "5474947" | "5488612" | "5498558" | "5508544" | "5600592" | "5618575" | "5677867" | "5801401" | "5852306" | "5880991" | "5923056" | "5936274" | "5952692" | "5959465" | "5981350" | "5986932" | "5991225" | "6009011" | "6025228" | "6025627" | "6031263" | "6069380" | "6069816" | "6124729" | "6134175" | "6141238" | "6141248" | "6143636" | "6163049" | "6169306" | "6208164" | "6210999" | "6229175" | "6238976" | "6246606" | "6249020" | "6249460" | "6307775" | "6317364" | "6341084" | "6351411" | "6377070" | "6424001" | "6461931" | "6475857" | "6514842" | "6541280" | "6574143" | "6586797" | "6730575" | "6754108" | "6778441").PN.	US-PGPUB; USPAT; USOCR
13	IS&R	L13	5	(("6635921") or ("6211531") or ("5604357") or ("6211531") or ("5952692") or ("6169308")).PN.	USPAT

14	BRS	L14	12	("4692997" | "5021839" | "5055887" | "5093699" | "5216262" | "5430011" | "5432362" | "5606177" | "5608231" | "5629231" | "5714766" | "5962864").PN.	US-PGPUB; USPAT; USOCR
15	BRS	L15	16	("6211531").URPN.	USPAT

	Type	L #	Hits	Search Text	DBs
16	BRS	L16	16	("6211531").URPN.	USPAT
17	BRS	L17	1	("5319229").PN.	US-PGPUB; USPAT; USOCR
18	BRS	L18	36	("5604357").URPN.	USPAT
19	BRS	L19	8	multi adj tunnel adj junction	USPAT

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	2007	vertical adj transistor	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	1036	1 and memory	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	7	second adj planar adj transistor	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
4	IS&R	L4	1	("7042107").PN.	USPAT
5	BRS	L5	0	("2005/0029559").URPN.	USPAT
6	BRS	L6	9	multi adj tunnel adj junction	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L7	561	multi adj2 junction	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L8	3	1 and 7	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB